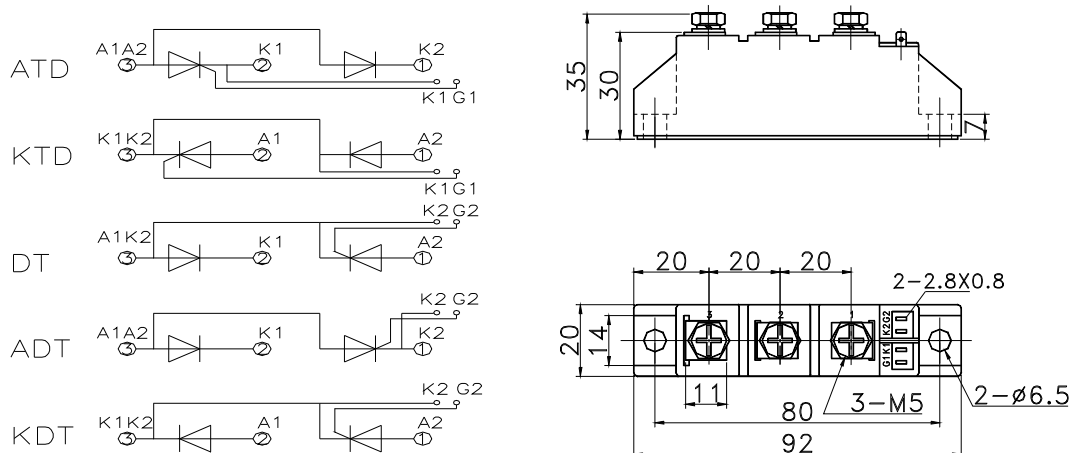


## TD55 ATD55 KT55 DT55 ADT55 KDT55

| SYMBOL                                   | CHARACTERISTIC                                                       | TEST CONDITIONS                                                                                                                             | T <sub>j</sub> (°C) | VALUE |      |       | UNIT                             |
|------------------------------------------|----------------------------------------------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------|---------------------|-------|------|-------|----------------------------------|
|                                          |                                                                      |                                                                                                                                             |                     | Min   | Type | Max   |                                  |
| I <sub>T(AV)</sub><br>I <sub>F(AV)</sub> | Mean on-state current                                                | 180° half sine wave 50Hz<br>Single side cooled, T <sub>c</sub> =85°C                                                                        | 125                 |       |      | 55    | A                                |
| I <sub>T(RMS)</sub>                      | RMS on-state current                                                 | Single side cooled, T <sub>c</sub> =85°C                                                                                                    | 125                 |       |      | 86    | A                                |
| V <sub>DRM</sub><br>V <sub>RRM</sub>     | Repetitive peak off-state voltage<br>Repetitive peak reverse voltage | V <sub>DRM</sub> &V <sub>RRM</sub> tp=10ms<br>V <sub>DSM</sub> &V <sub>RSM</sub> = V <sub>DRM</sub> &V <sub>RRM</sub> +200V<br>respectively | 125                 | 600   |      | 1800  | V                                |
| I <sub>DRM</sub><br>I <sub>RRM</sub>     | Repetitive peak current                                              | at V <sub>DRM</sub><br>at V <sub>RRM</sub>                                                                                                  | 125                 |       |      | 8     | mA                               |
| I <sub>TSM</sub>                         | Surge on-state current                                               | 10ms half sine wave                                                                                                                         | 125                 |       |      | 1.25  | KA                               |
| I <sup>2</sup> t                         | I <sup>2</sup> T for fusing coordination                             | V <sub>R</sub> =60%V <sub>RRM</sub>                                                                                                         |                     |       |      | 7.90  | A <sup>2</sup> s*10 <sup>3</sup> |
| V <sub>TO</sub>                          | Threshold voltage                                                    |                                                                                                                                             | 125                 |       |      | 0.85  | V                                |
| r <sub>T</sub>                           | On-state slop resistance                                             |                                                                                                                                             |                     |       |      | 3.47  | mΩ                               |
| V <sub>TM</sub>                          | Peak on-state voltage                                                | I <sub>TM</sub> =165A                                                                                                                       | 125                 |       |      | 1.50  | V                                |
| dv/dt                                    | Critical rate of rise of off-state voltage                           | V <sub>DM</sub> =67%V <sub>DRM</sub>                                                                                                        | 125                 |       |      | 800   | V/μs                             |
| di/dt                                    | Critical rate of rise of on-state current                            | From 67%V <sub>DRM</sub><br>to 165A, Gate source 1.5A<br>t <sub>r</sub> ≤0.5μs Repetitive                                                   | 125                 |       |      | 50    | A/μs                             |
| I <sub>GT</sub>                          | Gate trigger current                                                 | V <sub>A</sub> =12V, I <sub>A</sub> =1A                                                                                                     | 25                  | 30    |      | 100   | mA                               |
| V <sub>GT</sub>                          | Gate trigger voltage                                                 |                                                                                                                                             |                     | 0.8   |      | 2.0   | V                                |
| I <sub>H</sub>                           | Holding current                                                      |                                                                                                                                             |                     | 20    |      | 100   | mA                               |
| V <sub>GD</sub>                          | Non-trigger gate voltage                                             | At 67%V <sub>DRM</sub>                                                                                                                      | 125                 |       |      | 0.2   | V                                |
| R <sub>th(j-c)</sub>                     | Thermal resistance<br>Junction to heatsink                           | At 180° sine Single side cooled                                                                                                             |                     |       |      | 0.530 | °C /W                            |
| V <sub>iso</sub>                         | Isolation voltage                                                    | 50Hz, R.M.S, t=1min, I <sub>iso</sub> :1mA(MAX)                                                                                             |                     | 2500  |      |       | V                                |
| F <sub>m</sub>                           | Thermal connection torque(M5)                                        |                                                                                                                                             |                     |       | 0.20 |       | N·m                              |
|                                          | Mounting torque(M6)                                                  |                                                                                                                                             |                     |       | 0.30 |       | N·m                              |
| T <sub>stg</sub>                         | Stored temperature                                                   |                                                                                                                                             |                     | -40   |      | 140   | °C                               |
| W <sub>t</sub>                           | Weight                                                               |                                                                                                                                             |                     |       | 100  |       | g                                |
| Outline                                  | 201F3                                                                |                                                                                                                                             |                     |       |      |       |                                  |

## OUTLINE DRAWING & CIRCUIT DIAGRAM



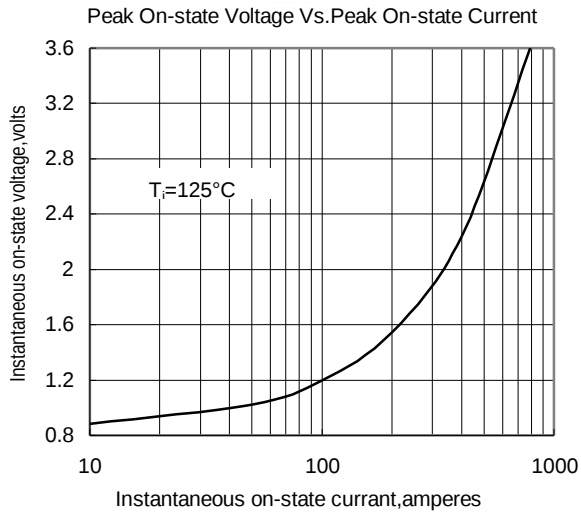


Fig.1

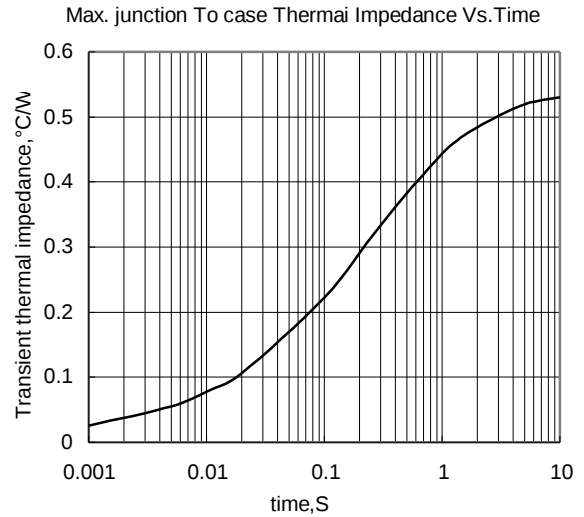


Fig.2

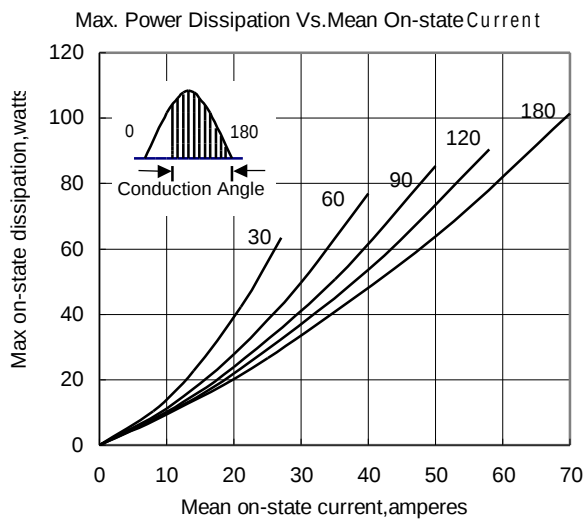


Fig.3

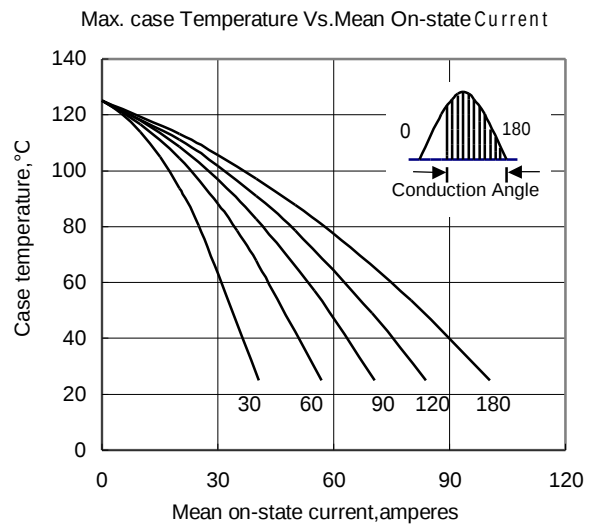


Fig.4

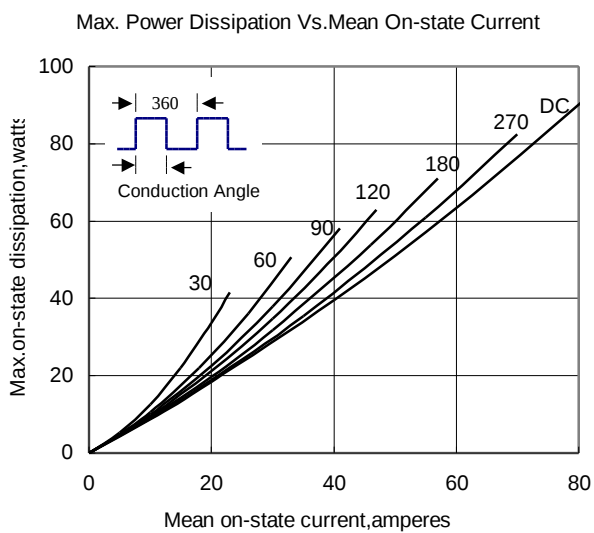


Fig.5

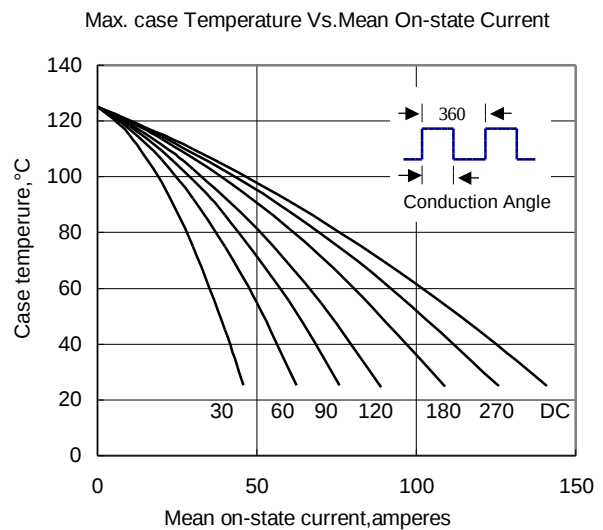


Fig.6

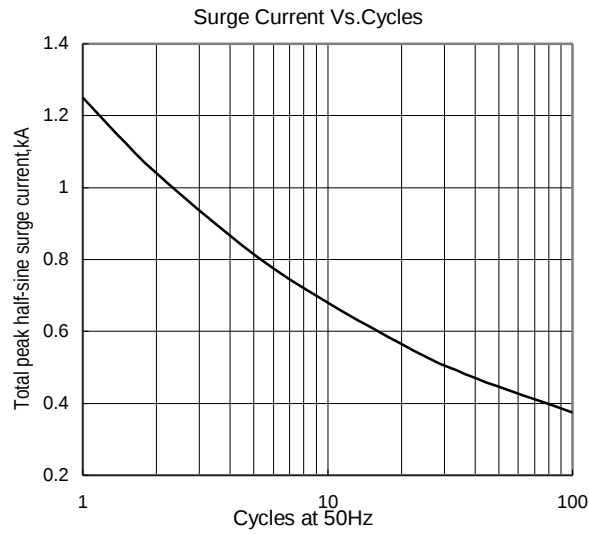


Fig.7

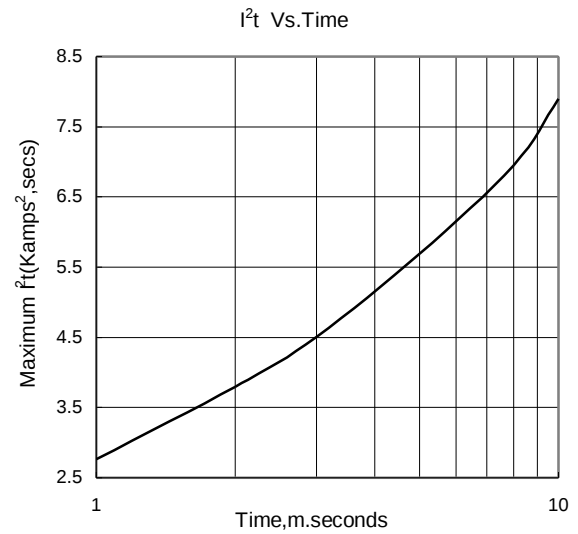


Fig.8

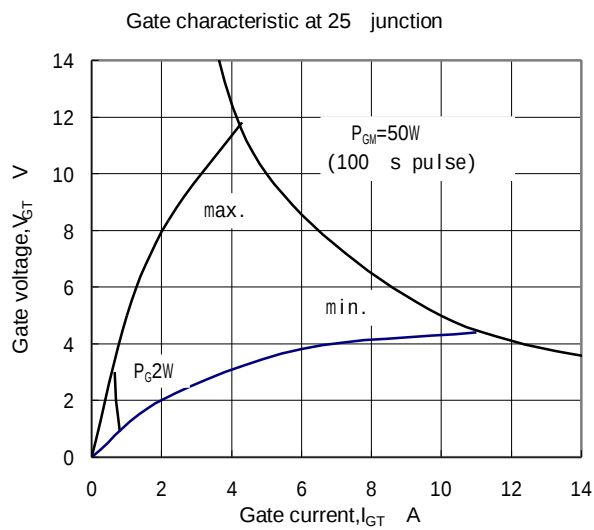


Fig.9

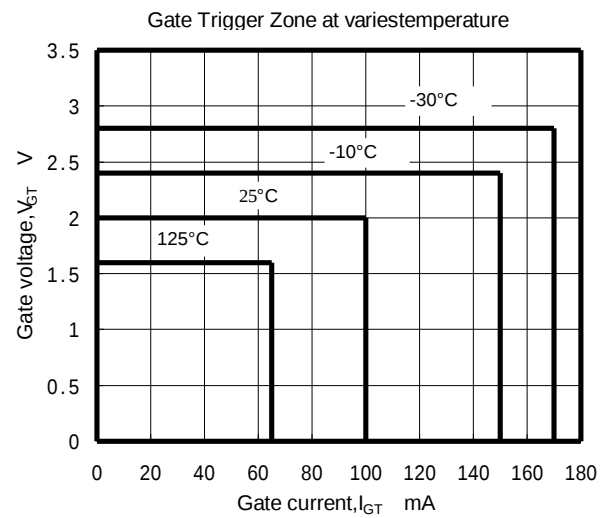


Fig.10